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# Metal Oxides and Their Composites for the Photoelectrode of Dye Sensitized Solar Cells

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# 1. Introduction

Nowadays, solar energy is one of the most promising future energy resources in concerns to the sustenance of life on Earth and the depletion of fossil fuels. It is projected that the fossil fuel related  $CO_2$  emissions rise from 32 to 42 billion metric tons in 2007 and 2035 (EIA., 2010). This enormous amount of  $CO_2$  emission will leads to a severe climatic change of the world and therefore a greatest anxieties for the scientific era of 21<sup>st</sup> century. This rigorous apprehension leads the scientist for the development of solar cell that utilizes solar energy, a renewable and carbon free energy source. The solar energy strike to the earth in one hour is about  $4.3 \times 10^{20}$  J, which is higher than all the energy consumed in the planet ( $4.1 \times 10^{20}$  J). Therefore, covering 0.1% of the earth's surfaces with solar cell of 10% efficiency would satisfy the current energy demand (Grätzel., 2001).

In general, solar cells can be classified as p-n junction semiconductor solar cells and organicbased exitonic solar cells (OESCs), in which polymer solar cell (PSC), dye sensitized solar cell (DSSC) and hybrid solar cell are included. In 1991, O'Regan & Grätzel first reported the dye sensitized nanocrystalline TiO<sub>2</sub> solar cell (DSSC) based on the mechanism of a first regenerative photoelectrochemical processes with an efficiency of 7.1-7.9 % (under simulated solar light) (O'Regan & Grätzel., 1991). Since then, extensive researches have continued to increase the power conversion efficiency (PCE) of DSSC by incorporating n-type metal oxide semiconductors such as TiO<sub>2</sub>, ZnO, SnO<sub>2</sub>, Nb<sub>2</sub>O<sub>5</sub>, SrTiO<sub>3</sub> etc and their composites as photoelectrode materials to achieve a reasonable efficiency of DSSCs of low cost, being therefore a promising alternative to conventional p-n junction solar cell. The wide band gap  $(E_g > 3eV)$  metal oxide semiconductors having suitable band position relative to sensitizer has been employed for the fabrication of DSSCs. The high surface area of nanoporous metal oxides facilitates the improvement of light absorption with improved dye loading for improved performance of DSSC. It is evident that the metal oxides employed for the fabrication of DSSCs has solar absorption below a threshold wavelength,  $\lambda_g$  (where,  $\lambda_g$  =  $1240/E_g$ ), i.e., they have absorption at ultraviolet region. On the other hand, dye is only responsible for the absorption of light at visible and near-infrared region. The strong absorption of light is attributed to the intramolecular charge transfer transition (ICT) from electron donating group to the anchoring acceptor group of dye. Therefore, the anchored

dye on to the metal-oxide surface helps the red shift of absorption threshold of metal oxide near infrared region (Rengaraj et al., 2005). In addition to the above physical characteristics, the inexpensiveness, natural abundancy and facile synthesis methods of metal oxides and their composites is another advantage for the application in DSSCs.

This chapter discusses the understanding the fundamental of DSSCs, different structural and technical aspect of metal oxides and their composites for the stepwise development of the performance of DSSCs. In addition, we focuses on the understanding of interfaces between metal oxides (or metal oxide composites)/dye/electrolyte, in which the electron injection and transport for improving the efficiency of DSSCs are related. Figure 1 represents the energy band diagram vs. vacuum of the metal oxides describes in this chapter.



Fig. 1. Energy band diagram of the representative metal oxides applied in DSSC (vs vacuum). The lower edge of the conduction band (CB) (black) and the upper edge of the valence band (VB) (red) are presents along with the band gap in electron volts (eV). Energy levels were taken from the following references (Grätzel., 2001; Wei et al., 2008; Hod et al., 2010)

## 2. Dye sensitized solar cell (DSSC)

Figure 2 shows a schematic representation of the operating principle of DSSC. Based on the electron transfer mechanism from dye to TiO<sub>2</sub> conduction band, DSSC can be classified into two distinct classes: Type-I, and type-II. The heart of the system is mesoporous semiconducting metal oxide (mostly employed TiO<sub>2</sub>) film that is placed in contact of a redox electrolyte (such as  $I^{-}/I_{3^{-}}$ ,  $Br^{-}/Br_{2}$ ,  $SCN^{-}/(SCN)_{2}$ ,  $SeCN^{-}/(SeCN)_{2}$ , bipyridine cobalt (III/II) complexes ) (Wang et al., 2005; Nusbaumer et al., 2001; Wang et al., 2004; Sapp et al., 2002; Bergeron et al., 2005) or a hole conductor (such as CuI, CuBr, CuSCN, spiro-MeOTAD) (Wu et al., 2008). A monolayer of the sensitizer (typically bipyridine ruthenium complexes) such as *cis*-diisothiocyanato-bis(2,2'-bipyridyl-4,4'-dicarboxylato)ruthenium(II) bis(tetrabutylammonium) (N719), *cis*-bis(isothiocyanato)bis(2,2'-bipyridyl-4,4'-dicarboxylato)-ruthenium(II) (N3), and *cis*-disothiocyanato-(2,2'-bipyridyl-4,4'-dicarboxylic



Fig. 2. Principle of operation of type-I & type-II dye sensitized solar cell (DSSC)

acid)-(2,2'-bipyridyl-4,4'-dinonyl)ruthenium(II) (Z907) etc is attached to the surface of the nanocrystalline metal oxide film in type-I DSSC (Thavasi et al., 2009). The type-I DSSC is understood as general electron transport mechanism, where the photoexcitation of dye results the injection of electron to the conduction band (CB) of the metal oxides from the excited dye, i.e. from the LUMO level. On the other hand, in type-II DSSCs, enediol group, catechol and its derivatives such as dopamine, fluorone, and anthocyanins having catechol moieties gives strong direct dye-to-metal-oxide (TiO<sub>2</sub>) charge transfer (DTCT) bands. Therefore, electrons are injected directly from HOMO of dye to the conduction band (CB) of metal oxide rather than from the excited state (LUMO) under illumination (i.e. one-step electron injection) (Tae et al., 2005). A platinized cathode is employed to collect the electrons from the conduction band of metal oxide anode injected from the excited dye and to catalyze the redox couple viz. I-/I<sub>3</sub>- regeneration reaction. The redox couple of the electrolyte also reduces the oxidized dye. The iodide regenerated, in turn, by the reduction of triiodide at the cathode, with the circuit being completed via electron movement through the external load. The voltage generated under illumination is the difference between the Fermi level of the electron in metal oxide and the redox potential of the electrolyte. Overall, the device

generated electric power from sunlight without suffering any enduring chemical conversion (Grätzel., 2003; Bisquert et al., 2004). Whereas, in type-II DSSC faster back electron transfer limit its conversion efficiency, over and above commercial application (Huber et al., 2000; Wang et al., 2003). In this chapter, the application of metal oxide and their composites is mainly focused in type-I DSSC.

#### 2.1 Photochemical processes in DSSCs and rate limiting steps

The photoelectrochemical process in DSSC can be expressed by the following reaction a-f. Where, electron injection (reaction b) of the photoexcited dye to the conduction band (CB) of metal-oxide (TiO<sub>2</sub>) occurs in subpicosecond range (200 fs for coumarin dye to TiO<sub>2</sub>) (Hara et al., 2000). Reaction (c) and (d) represents the regeneration of photoexcited dye by the oxidation of I- to I<sub>3</sub>- and the reduction of I<sub>3</sub>- to I- by Pt catalyst at cathode respectively. Reaction (e) and (f) correspond to the dark reaction occur during the photoconversion and do not play a significant negative impact on the photovoltaic performance of DSSC due to their sluggish reaction rate compared to the reaction (b).

Metal oxide (TiO <sub>2</sub> )  D+hv	$\rightarrow$ Metal oxide (TiO <sub>2</sub> )  D*	excitation	(a)
Metal oxide $(TiO_2)$   D*	$\rightarrow$ Metal oxide (TiO <sub>2</sub> )   D++e	e- <sub>(CB)</sub> injection	(b)
Metal oxide (TiO <sub>2</sub> ) D++3I-	$\rightarrow$ Metal oxide (TiO2)  D+I <sub>3</sub>	- regeneration	(c)
$I_{3}$ -+ 2e- (Pt)	$\rightarrow$ 3I-	reduction	(d)
$I_{3}$ -+ 2e-(CB)	$\rightarrow$ 3I-	reception (dark reaction)	(e)
Metal oxide (TiO <sub>2</sub> )   D <sup>+</sup> +e <sup>-</sup> (CB)	$\rightarrow$ Metal oxide (TiO <sub>2</sub> )  D	recombination (dark reaction)	(f)

Photovoltaic performance is significantly influenced by the events in interfaces between the metal oxide semiconductor, the dye, and the electrolyte. The dye/metal oxide interface is such that the oxidation potential of excited dye (LUMO) is sufficiently negative to obtain the effective electron injection to the conduction band of metal oxide. Upon photoirradiation, dye molecule undergoes a  $\pi \to \pi^*$  transition thereby exciting an electron to the LUMO due to the relatively weak lateral overlapping of atomic orbital's ( $\pi$  bonds) with loosely bound electrons ( $\pi$  electrons) in HOMO. These excited electrons diffuse into the dye/metal oxide interface. Hence, a built in energy gradient ( $\Delta E$ ) exists between the dye/metal oxide interface due to the energy difference between the LUMO state of dye and the CB of metal oxide ( $E_{CB}$ ). Thus, electrons in the LUMO of photoexcited dye undergo a nonradiative transition to the conduction band of metal oxide within a few picoseconds and thereby oxidized. The oxidized dye is reduced back to its ground state by using a redox couple together with platinum as catalyst at cathode (Thavasi et al., 2000; Jose et al., 2009).

The fundamental phenomenon of photoconversion and rate limiting steps involved in DSSCs (type-I) depicted in figure 2 are listed below:

- I. The rate of excitation of dye: it is determined by the absorption of the number of photon at the absorption wavelength of dye, intensity of solar radiation at that window, and the absorption cross-section of dye.
- II. The relaxation/radiative recombination of the excited electron of dye from LUMO to HOMO, and the corresponding rate constant  $k_1$ : Relaxation processes occur typically in a time scale of nanoseconds. This process reduces the excited state free energy by ~ 400 meV. The typical rate of excited state decay to ground state of dye is in the range 10<sup>7</sup>-10<sup>10</sup> s<sup>-1</sup> (Grätzel & Durrant., 2008).
- III. Exciton diffusion length D<sub>EXT</sub>.

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- IV. Interfacial electron transfer, i.e., the injection of excited electron from the LUMO of dye to the conduction band of metal oxide with the rate constant  $k_2$ : The kinetics of the interfacial electron transfer dynamics strongly depends on the energetic of metal oxide/dye/electrolyte interface and the density of electron in metal oxide (*i.e.* the Fermi level of metal-oxide). The interfacial charge transfer occurs in a time scale of several picoseconds. In model system studies of dye sensitized metal oxide films, electron injection rate of >  $10^{12}$  s<sup>-1</sup> have reported for a range of sensitizer (Grätzel & Durrant., 2008).
- V. Injected electron transport through the mesoporous layer of metal oxide to the transparent conducting oxide (TCO). It is controlled by the diffusion coefficient of electron ( $D_e$ ), and the electron lifetime ( $\tau_e$ ).
- VI. Phonon relaxation, through which an electron loses its energy by electron-phonon recombination.
- VII. Interfacial charge recombination, i.e., the capturing of electron from the conduction band (CB) of metal oxide by the oxidized dye with the rate constant  $k_3$ : Charge recombination occurred from the CB of photoelectrode to oxidized dye in the range of µs-ms. This recombination rate is strongly depends on the electron density of the photoelectrode, light intensity, and cell voltage.
- VIII.Back electron transfer, i.e., the capturing of CB electrons by the oxidized mediator in the electrolyte (e.g.  $I_{3}$ ) with the rate constant  $k_4$ : Back electron transfer typically very slow (in the range of ms-s) and the rate constant is strongly dependent on the concentration and viscosity of the electrolytes as well as the structure of dye (Grätzel & Durrant., 2008).
- IX. Regeneration of dye, i.e., the transfer of electron to the oxidized dye from the redox mediator in the electrolyte with the rate constant  $k_5$ : The restoration of the oxidized dye takes place in the nanosecond range. It is typically 100 times quicker than any recombination reaction and about 108 times faster than the inherent lifetime of the oxidized dye (Grätzel & Durrant., 2008).

In case of N719 dye, the interfacial charge recombination and the regeneration rate constants are  $k_3 = 1.4 \times 10^3$  s<sup>-1</sup> and  $k_5 = 1.1 \times 10^5$  s<sup>-1</sup>, respectively. This implies the injection yield of 99%, since the regeneration step is ~100 times faster than recombination. Also, the rate of the injection of electron ( $k_2 > 1.4 \times 10^{11} \text{ s}^{-1}$ ) is three order of magnitude faster than the radiative recombination (Grätzel & Durrant., 2008). Consequently, it is assumed that interfacial charge recombination and radiative recombination, the two rate limiting processes, do not limit significantly the photoconversion of DSSCs. In addition, the exciton diffusion could be neglected since the exciton is highly localized on dyes because the particle radius is significantly smaller than the Bohr radius. Thus, the rate limiting processes that contribute highly on the photoconversion efficiency are (I), (IV), (V), (VI), (VIII) and (IX). The rate limiting steps, (I) and (IX) are dependent on the dyes and electrolyte, respectively. Steps (IV) and (VIII) depend on the interface between metal oxide/dye and metal oxide/electrolyte interface. The other two steps, (V) and (VI), are completely depends on photoelectrode (Jose et al., 2009). It is clear that the metal oxides, one of the major constituent of the photoelectrode, play a significant role on the performance of DSSCs by involving with most of the operation processes in the DSSCs.

#### 2.2 Characterization techniques of DSSCs

Photoelectric current-voltage (I-V) measurement, electrochemical impedance spectroscopic measurement (EIS), and incident photon to current conversion efficiency (IPCE) measurements are the major essential techniques for the characterization of DSSCs.

#### 2.2.1 Photoelectric current-voltage (I-V)

The photovoltaic performance of DSSCs is estimated from the current-voltage (I-V) measurements. The photovoltaic parameters of DSSCs are open circuit potential ( $V_{oc}$ ), short circuit current ( $I_{sc}$ ), fill factor (FF), and efficiency ( $\eta$ ). These parameters are measured under the standard condition of cell temperature 25 °C, incident solar radiation of 100 mW/cm<sup>2</sup>, and the spectral power distribution of AM1.5. Figure 3A depicts the I-V characteristics of a DSSCs made with N719 sensitized TiO<sub>2</sub> (degusa P25) photoelectrode of active area 0.2 cm<sup>2</sup> (Figure 3B). It is assumed that the standard redox potential of electrolyte is constant and, therefore, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant. However, the V<sub>oc</sub> of a photoelectrochemical cell should also constant.



Fig. 3. (A) Photovoltaic performance of a state-of-the-art DSSC laboratory cell: I-V curve measured under AM 1.5 standard test conditions and (B) Scanning electron micrograph (SEM) of a sintered mesoporous TiO<sub>2</sub> (Degusa P25) film supported on FTO

Short circuit current density ( $J_{sc}$ ) is the photocurrent per unit active area (A) of the photoelectrode when the applied potential across the DSSCs is zero, i.e.  $J_{sc} = I_{sc}/A$ . Under the ideal illumination condition,  $J_{sc}$  is effectively dependent on the efficiency of charge injection from the excited dye to the CB of metal oxide. The electron injection efficiency of some widely used metal oxides is found to be the following order:  $TiO_2 > Nb_2O_5 > SnO_2~ZnO$  (Thavasi et al., 2009).

Fill factor (*FF*) is the most important parameters of a photovoltaic cell. It is defined as the ratios of maximum power output ( $I_{max}xV_{max}$ ) and the product of  $V_{oc}$  and  $I_{sc}$ . Therefore, from figure 4,

$$FF(\%) = \frac{I_{max} \times V_{max}}{I_{sc} \times V_{OC}} = \frac{AreaA}{AreaB}$$
(1)

It can be concluded that the more square like I-V curve is essential for highly desired FF. The lowering of electron loss between the FTO/electrolyte interface increases the shunt resistance, thereby increases the fill factor. On the other hand, increase of the back electron transfer and

charge recombination is responsible for poor FF. Finally, comparing the ratios of total power out put ( $P_{out}$ ) with the solar power input ( $P_{in}$ ), efficiency ( $\eta$ ) can be measured. i.e.,

$$\eta = \frac{P_{out}}{P_{in}} = \frac{J_{sc}V_{oc}FF}{P_{in}}$$
(2)



Fig. 4. I-V curve and parameters of DSSCs output current (solid line) and power (blank line) as function of voltage

#### 2.2.2 Electrochemical Impedance Spectroscopy (EIS)

For better understanding the electron transport kinetics in DSSCs, EIS is the most powerful tools. EIS is a steady state process for evaluating the current response to the application of an ac voltage as function of frequency. EIS has been broadly employed to investigate the kinetics of electrochemical and photoelectrochemical processes including the clarification of salient ionic and electronic processes occurring in the DSSCs.

Figure 5 depicts a characteristics impedance spectrum (Nyquist plot) along with the electrical transmission line model of equivalent circuit for DSSC. The transmission line model is purely a combination of resistance (R) and capacitance (C). The series resistance, together with the sheet resistance of fluorine-doped tin oxide (FTO) glass and the contact resistance of the cell is denoted by Rs. Rco and Cco are the series resistance and the capacitance of the FTO/metal oxide interface, respectively. R<sub>TCO</sub> and C<sub>TCO</sub> are the charge transfer resistance and subsequent double layer capacitance of the FTO/electrolyte interface respectively. The transport resistance in the metal oxide film is represented by rt. The charge transfer resistance and the charge recombination processes between electrons in the metal oxide phototelectrode and electrolyte is determined by  $r_{CT}$ .  $C_{\mu}$  is the chemical capacitance of the metal oxide film. Z<sub>d</sub> is the Warburg diffusion of ions in the electrolyte. Finally, R<sub>Pt</sub> and C<sub>Pt</sub> are the charge transfer resistance and the double layer capacitance of the platinized FTO counter electrode respectively. Therefore, the steady state process of electron transport resistance through metal oxide film, ion diffusion through electrolyte, chemical capacitance at interface of the metal oxide/electrolyte, double layer charge transfer capacitance at interface of the FTO/electrolyte, and the platinized FTO counter electrode, can be estimate by using this method (Fabregat-Santiago et al., 2007).



Fig. 5. Typical impedance spectra of DSSCs (Nyquist plot) and its electrical transmission line model of equivalent circuit (The transmission line model is redrawn with permission from ref. Fabregat-Santiago et al., 2007. Copyright 2010, The American Chemical Society)

#### 2.2.3 Incident proton to current conversion efficiency (nipce)

IPCE is the measurements of spectral response of the cell that contain the partial information of quantum efficiencies of photocurrent generation processes such as the light harvesting ( $\eta_{LH}$ ), electron injection ( $\eta_{INJ}$ ), and charge collection efficiency ( $\eta_{COL}$ ). Therefore,

$$\eta_{\text{IPCE}}(\lambda) = \frac{J_{\text{SC}}(\lambda)}{q\phi(\lambda)} = \eta_{\text{LH}}(\lambda)\eta_{\text{INJ}}(\lambda)\eta_{\text{COL}}(\lambda)$$
(3)

Where,  $J_{sc}$  is the short circuit current density of the DSSCs at incident monochromatic light with incident wavelength  $\lambda$ . q and  $\varphi$  is the elementary charge and photon flux respectively (Gentilini et al., 2010). Following each step of conversion,  $\eta_{LH}$  is associated with the ability of the dye in absorbing photons.  $\eta_{INJ}$  quantifies the charge transfer from the LUMO of dye molecule to the conduction band of metal oxide. Finally, the collection efficiency  $\eta_{COL}$  is the amount of electrons that effectively reach the anode, avoiding recombination. It should be noted that IPCE measurement is performed under short circuit condition, where electron lifetime is higher. It is noteworthy that the high fraction of incident photon to current conversion (IPCE) is most important for efficient DSSCs and the mesoporous metal oxide with high surface area is the prerequisite for higher IPCE value.

#### 3. DSSC photoelectrodes with different metal oxides and their composite

As mentioned above, the different metal oxides and their composites have been investigated for the fabrication of DSSC. Herein, some of the important and highly explored metal oxides and their composites as DSSCs photoelectrode will be discussed.

#### 3.1 Titania (TiO<sub>2</sub>) / titania composite based photoelectrodes

Nature has abundantly the titanium dioxide (TiO<sub>2</sub>) which is relatively inexpensive, and nontoxic. From the time of invention of its photocatalytic activity by Fujishima and Honda in 1972 (Fujishima & Honda.,1972), it has been used in a wide range of application such as paint, pigment, water splitting, hydrogen and oxygen gas sensor, polluting gas sensor, and biosensors (Rahman et al., 2010). The n-type semiconductor TiO<sub>2</sub> has been existed naturally as three crystalline polymorphs, explicitly anatase, rutile, and brookite as shown in figure 6. The crystalline characteristics along with the band gap of TiO<sub>2</sub> ploymorphs has been tabulated in table 1.



Fig. 6. Different naturally occurs crystalline polymorph of  $TiO_2$  (A) anatase, (B) rutile, (c) brookite, where small red sphere:  $O^{2-}$ , big grey sphere:  $Ti^{4+}$ 

Polymorphs	Band gap	Space group	Cell parameter (Å)	Crystal structure
Anatase	3.23 eV	I 4 <sub>1</sub> /amd	a= 3.7845, c=9.5143	Tetragonal
Rutile	3.05 eV	P 4 <sub>2</sub> /mnm	a= 4.5937, c= 2.9587	Tetragonal
Brookite	3.26 eV	P bca	a= 9.1840, b= 5.4470, c= 5.1450	Orthorhombic

Table 1. Crystal characteristics of different TiO<sub>2</sub> polymorphs along with their band gap

In addition, TiO<sub>2</sub> exists in many other metastable forms such as monoclinic, tetragonal, orthorhombic, and cubic. The electronic state of Ti in TiO<sub>2</sub> is Ti<sup>4+</sup> (*3d*<sup>0</sup>), in which the valence band of TiO<sub>2</sub> is composed of the hybridized 2*p* orbital of oxygen and the *3d* orbital of Ti, while the conduction band is completely composed of pure *3d* orbital of Ti. Hence, the different parity of valence band and the conduction band of TiO<sub>2</sub> decreases the transition of electrons to the valence band; consequently, decrease the electron hole (e<sup>-</sup>-h<sup>+</sup>) recombination probability. Among the polymorphs of TiO<sub>2</sub>, it has known that rutile is the most stable and common. However, the Fermi level of anatase is 100 mV higher than that of rutile, which leads to higher open circuit potential (V<sub>oc</sub>). Moreover, the greater surface area of anatase is responsible for efficient dye loading, leads the higher photocurrent, consequently, higher photovoltaic performance. Brookite is less prominent for DSSC due to its complicated and difficult synthesis process. It is noted that the oxygen vacancies and the titanium interstitials as well as the decreased recombination probability with increased surface area makes TiO<sub>2</sub> an attractive materials for the application in DSSCs (Li et al., 2007; Jose et al., 2009).

#### 3.1.1 TiO<sub>2</sub> Photoelectrode with passivation layer and 1-D nanostructures

TiO<sub>2</sub> of anatase nanocrystalline form has been explored extensively in DSSCs photoelectrode due to its suitable band position, high surface area for improved dye loading, and facile synthesis procedure. However, the lack of efficient electron transfer through the FTO/TiO<sub>2</sub> interface increases the back electron transfer to the redox ion in electrolyte (Figure 7A) and low light harvesting with low absorption in red region limits the conversion efficiency of DSSCs. Moreover, the random electron diffusion (i.e. electron trapping) and the enhanced grain boundary density of spherical TiO<sub>2</sub> nanoparticles (Figure 7C) increase the loss of conversion efficiency with the increase of carrier recombination (Benkstein et al., 2003). Therefore, extensive efforts have been performed to minimize the back electron transfer/recombination. For example the carrier leakage of direct electron acceptance from the nanocrystalline TiO<sub>2</sub> film can be avoided through prevention of hole mediation to excited dye by addition of 4-tert-butylpyridine into redox solution (Hattori &Goto, 2007). Other impressive ways are the use of TiO<sub>2</sub> passivating layer/blocking layer by using rutile TiO<sub>2</sub> mixed with anatase TiO<sub>2</sub>, and the fabrication of DSSCs by one dimensional (1-D) nanostructures such as nanotube, nanowire, nanorod etc( Zhu et al., 2006).



Fig. 7. Schematic representation of spherical anatase  $TiO_2$  nanoparticles based DSSCs, where back electron transfer/recombination is the major role for loss of conversion efficiency (A), photoelectrode with lower passivation layer and upper anatase mesoporous  $TiO_2$  to minimize the back electron transfer (B), random electron diffusion through spherical  $TiO_2$  nanoparticles (C), and 1-D nanostructures of  $TiO_2$  with directional electron diffusion (D)

The important routes of the back electron transfer to electrolyte are to via nanocrystalline  $TiO_2$  and via TCO substrate. However, the back transfer from FTO to the  $I/I_3$ - redox couple is negligible because the Fermi level of FTO is close to the redox Fermi level at open circuit potential. Thus, the direct route of recombination of  $I/I_3$ - redox couple is to via the nanocrystalline  $TiO_2$ . Many researches are focused to prevent this back electron transfer by using a lower passivating layer (rutile/rutile mixed  $TiO_2$ ) with an upper layer of mesoporous

anatase TiO<sub>2</sub> film. The compact TiO<sub>2</sub> layer not only act as a shielding layer against the ionic penetration but also provoke different microstructure in the sol-gel derived TiO<sub>2</sub> electrodes, which in turn leads to different amount of dye absorption (Yu et al., 2009). All the DSSCs with passivating layer shows higher efficiency than that of without passivating layer. The increase of J<sub>SC</sub> is generally related to the enhancement of the number of photogenerated electrons that efficiently transferred to TiO<sub>2</sub> electrode. The TiO<sub>2</sub> passivating layer has both of rutile and anatase phases (3.05 eV <Eg> 3.23 eV) and the upper mesoporuos TiO<sub>2</sub> film has only anatase phase (Eg = 3.23 eV). So, the injected excited electrons move in the direction of lower energy conduction band from the porous TiO<sub>2</sub> to the passivating layer, thus resulting in a smooth electron movement and reduce the back electron transfer (Figure 7B). In Table 2, we tabulate the comparison performance of DSSCs before and after using TiO<sub>2</sub> (rutile) passivating layer along with the deposition techniques of passivation layer and mesoporous layer.

Materials	Deposition	Process for	Efficiency	Ref.
	techniques of	making	with (without)	
	passivation	mesoporous	passivation	
	layer	TiO <sub>2</sub> layer	layer	
A thin passivating	Facing target	Sol-gel	2.85% (0.79%)	Hossain et
TiO <sub>2</sub> (rutile)	sputtering			al., 2008
underlayer	(FTS) method			
A thin passivating	Sputtering	Sol-gel	5.25% (3.85%)	Hattori &
TiO <sub>2</sub> (rutile)	method	-		Goto, 2007
underlayer				
A thin compact TiO <sub>2</sub>	Dip-coating	Sol-gel	7.6% (5.7%)	Yu et al.,
(rutile)layer	- 0	Ç	. ,	2009

Table 2. Performance of DSSCs after using passivating layer and their deposition process

Another important technical phase for the improvement of performance of DSSCs is to use 1-D TiO<sub>2</sub> nanostructures. Figure 7D shows the 1-D nanostructures and their directional electron diffusion. Frank and coworkers investigated the comparative study of electron transport and recombination in DSSCs between TiO<sub>2</sub> nanotubes (TNTs) and spherical nanoparticles (NPs) by frequency-resolved modulated photocurrent/photovoltage spectroscopy (Zhu et al., 2006). The rate of recombination in TNTs photoelctrode is much slower than that of NPs photoelectrode. This increase the charge collection efficiency in TNTs photoelectrode compare to NPs photoelectrode. The internal and external dye loading with stronger internal light-scattering effects of TNTs exhibits higher photoconversion efficiency. However, the dye loading of TNTs and charge collection efficiency is strongly dependent on the nanotube arrays. Bundling of nanotube creates additional pathway via intertube connection and decrease the internal surface area of the films accessible to dye molecules. Therefore, bundling of nanotubes increases the charge recombination and decreases the photoconversion efficiency. It was established that the high photocurrent density and photocurrent efficiency could be achieved by better-aligned nanotube arrays. Capillary stress creates the morphological disorder (e.g. bundling and microcracks) of TNTs during the solvent evaporation. Therefore, supercritical CO<sub>2</sub> drying process is developed for preparing crack-free and bundle-free nanotubes (Zhu et al., 2007). Many strategies have developed for the fabrication of TNTs such as direct electrochemical anodization of Ti foil,

electrophoresis, hydrothermal method, and incorporation of TiO<sub>2</sub> into anodized alumina oxide (AAO).

1 <b>-</b> D	Preparation method	Efficiency of 1-D	Efficiency of	Ref.
nanostructures		nanostructures	NPs based	
		based DSSCs	DSSCs	
TiO <sub>2</sub> nanorod	Oriented attachment	6.2%	4.2%	Kang et al.,
	of nanoparticles			2008
TiO <sub>2</sub> nanorod	Solvothermal	7.9%	5.5%	Marco et al., 2010
TiO <sub>2</sub> nanofibre/	Electrospinning and	10.3%	9.25%	Chuangchote
TiO <sub>2</sub> nanoparticle	sol-gel techniques			et al., 2008
Macroporous	Hydrothermal	0.86%	-	Wang et al.,
TiO <sub>2</sub> nanowires	synthesis			2009
TiO <sub>2</sub>	Electrochemical	3%	-	Zhu et al., 2007
Nanotubes	anodization of Ti foils			

Table 3. Comparison performance of different 1-D nanostructures photoelectrode with NPs based photoelectrode for the application in DSSCs

The other 1-D nanostrucutres are nanorods, nanowires, etc. Recently, Manca and coworkers have developed a novel and cost efficient method for the preparation of anatase  $TiO_2$ nanorod (20-30 nm × 100-300 nm) by single-step solvothermal process (Marco et al., 2010). This single step solvothermal process does not require the complete removal of organic residual that will act as a binder. This TiO<sub>2</sub> nanorod showed improved photoconversion performance compared with the naocrystalline counterparts due to the increased rate of electron transport arisen from the high crystallinity of the nanorod. However, many reports suggested that the poor extent of dye loading and the poor light harvesting of nanorod based DSSC is due to the low specific surface area of the nanorod. To facilitate the improved dve loading, Kang et al. synthesized TiO<sub>2</sub> nanorod (4 nm  $\times$  20 nm) of high specific surface area from the necking of truncated NPs by "oriented attachment approach" (Kang et al., 2008). The improved roughness factor of the nanorod (169.9 µm<sup>-1</sup>) compare to nanoparticles (115.6 µm<sup>-1</sup>) showed higher dye absorption ability and thereby improved conversion efficiency. Intentional integration of metal impurities into the semiconducting materials is very useful and common approach for tuning the semiconducting properties such as band gap and electrical conductivity. Feng et al. prepared successfully tantalum (Ta)-doped TiO2 nanowire by low temperature hydrothermal method. Ta-doped TiO<sub>2</sub> nanowire gives a very high photovoltage (0.87 V) of comparable  $J_{sc}$  with undoped naowire in a liquid-state DSSCs (Feng et al., 2009). The high open circuit potential close to the theoretical maximum might be attributed to the negative shift of flat band potential of nanowires. In table 3 we tabulate the comparison performance of DSSCs made by 1-D TiO2 nanostructures and TiO2 nanoparticles.

#### 3.1.2 TiO<sub>2</sub> photoelectrode with scattering layer

The efficiency of DSSCs over 11% in laboratory scale has been reported (Grätzel, 2003). The ultimate target of DSSCs technology is the up scaling of the small cell into larger modules. Therefore, many important factors have to be considered such as stability, durability, and

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more importantly price per watt of the module to bring the modules into market. Photosensitizing dye of high efficient DSSCs is still very expensive, so the actual cost-energy per watt of DSSCs module relies on the amount of dye usage. Many strategies such as development of organic dye, replacement of platinum by carbon materials and organic polymer have been developed for the reduction of energy cost of DSSCs. However, one remarkable strategy has been developed on the modification of TiO<sub>2</sub> photoelectrode is the uses of scattering (SC) TiO<sub>2</sub> particles (films or mixed with nanocrystalline particles). These SC layer/particles will help to develop very thin nanocrystalline TiO<sub>2</sub> film of high surface area that will reduce the dye usage without sacrificing the cell efficiency. Figure 8 shows the light confined effect on different TiO<sub>2</sub> particles. It can be seen that SC TiO<sub>2</sub> particles scattering property is strongly dependent on the refractive index between the active TiO<sub>2</sub> film, scattering property is strongly dependent on the refractive index between the active TiO<sub>2</sub> film, scattering layer, and on the relative size of the scattering particles (Shin et al., 2010; Arakawa et al., 2006).



Fig. 8. Conceptual scheme of Light confined effect (reproduced with permission from ref. Arakawa et al., 2006. Copyright 2010, IEEE)

Scattering layer	V <sub>oc</sub> (mV)	J <sub>sc</sub> (mAcm <sup>-2</sup> )	FF (%)	η (%)	Ref.
(SC) matrix	with SC	with SC	with SC	with SC	
	(without SC)	(without SC)	(without SC)	(without SC)	
	layer	layer	layer	layer	
TiO <sub>2</sub> film of 300	735 (680)	14.5 (12.3)	No appreciable	7.48 (5.77)	Kim et
nm particles			change		al., 2008
sub-micrometer- sized Al <sub>2</sub> O <sub>3</sub>	745 (730)	14.44 (12.54)	71.1 (67.7)	7.3 (6.5)	Shin et al., 2010
ZrO <sub>2</sub> (500-1000 nm)	738 (710)	12.72 (6.42)	61.8 (70.2)	5.8 (3.2)	Hore et al., 2006
ZnO microsheets	677 (636)	8.68 (6.04)	43.98 (46.58)	2.58 (1.79)	Yi et al., 2010

Table 4. Summarization of the performance of different scattering particles based photoelectrode for the application in DSSCs

Hore et al. investigated the comparison study of the performance of different thickness (4  $\mu$ m, 8  $\mu$ m) of nanocrystalline TiO<sub>2</sub> film of high surface area with and without scattering layer (Hore et al., 2006). It was observed that the 4  $\mu$ m nanocrystalline TiO<sub>2</sub> thin film with SC layer shows a comparable performance with 8  $\mu$ m thick TiO<sub>2</sub> film without SC layer. Therefore, it is expected to use thin film of TiO<sub>2</sub> with SC layer for the industrial production of large DSSC modules, which will minimize the cost of dye by lesser consumption in the production procession. Some other metal oxide has also explored as effective SC layer on top of the active TiO<sub>2</sub> film such as ZrO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub>, TiO<sub>2</sub>-rutile form, ZnO etc. Table 4 summarizes the comparison of photoconversion efficiencies with different scattering particles.

#### 3.1.3 Metal-doped titania (TiO<sub>2</sub>) photoelectrode

Metal-ions as dopant has a significant effect on the electrical surface state modification of TiO<sub>2</sub>. This modification leads to significant change of electrical conductivity, shifting of Fermi level potential, particle aggregation, charge transfer kinetics, and dye absorption characteristics of TiO<sub>2</sub>. However, many reports have suggested that the performance of DSSCs at the optimized level of metal-ions doping into TiO<sub>2</sub> differ mainly the tuning of flat band of TiO<sub>2</sub>. Lü et al. synthesized well-crystalline niobium (Nb) doped anatase TiO<sub>2</sub> (Nb-TiO<sub>2</sub>) and investigated its effect on the performance of DSSCs (Lü et al., 2010). It was revealed that Nb doping level of 2.5 -7.5 mol% has positive effect on the short circuit current with positive shift of flat band potential. This increment of the photocurrent was attributed to the enhanced electron injection, increased charge transfer kinetics as well as the improvement of dye loading up to 5.7±0.2x10-8 [mol cm-2] at a doping level of 7.5 mol% compared to the undoped state. The TiO<sub>2</sub> doped by various metals such as tungsten (W), neodymium (Nd) also exhibited the similar phenomenon (Ko et al., 2005; Yao et al., 2006), while Al doped TiO<sub>2</sub> showed an opposite effect (Ko et al., 2005). Lee et al. deposited a thin film of compact Nb-doped TiO<sub>2</sub> on FTO by pulsed laser deposition (PLD) (Lee at al., 2009). The performance of the DSSC of compact Nb-doped TiO<sub>2</sub> layer with an upper mesoporous  $TiO_2$  layer is prominent compared to the compact  $TiO_2$  layer.

Figure 9 describes the band diagram of two compact layers and the charge transfer kinetics. The upper part of the diagram is before contact with FTO and it can be seen that the Fermi level of compact TiO<sub>2</sub> and Nb-doped TiO<sub>2</sub> layers is below and above of the conduction band (E<sub>CB</sub>) respectively. This is ascribed by the degeneracy of Nb-doped TiO<sub>2</sub> and the nondegeneracy of compact TiO<sub>2</sub>. When compact TiO<sub>2</sub> and FTO are in contact (i.e. semiconductor-metal contact), a depletion region or Schottky barrier, q ( $\varphi_m$ - $\varphi_s$ ) is form by the difference of work function of FTO ( $\phi_m$ ) and TiO<sub>2</sub> ( $\phi_s$ ). Electrons have to overcome this barrier in order to be transferred from compact TiO<sub>2</sub> to FTO. Hence, the electron injection efficiency is decreased while the back electron transfer was increased. On the other hand, the contact between FTO and the compact degenerate Nb-doped TiO<sub>2</sub> layer form a very narrow depletion region. Electrons injected rapidly from compact Nb-doped TiO<sub>2</sub> to FTO by tunneling leads to ohmic contact characteristics (Lee et al., 2009). Therefore, the incorporation of compact Nb-doped TiO<sub>2</sub> layer remarkably reduces the interfacial charge transfer resistance and results in the enhancement of the performance of the DSSC. The performance of some of the metal-doped TiO<sub>2</sub> nanocompisites in DSSCs is summarized in table 5. From the experimental data of table 5, it is clearly observed that doped metal ions have a strong effect for the tuning of flat band potential, as well as the electron injection efficiency.

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Fig. 9. Schematic illustration of band diagram of compact TiO<sub>2</sub> and compact Nb-TiO<sub>2</sub> layer before (upper) and after (under) contact with FTO (redrawn with permission from, Lee at al., 2009. Copyright 2010, The American Chemical Society)

Dopant	Synthesis	V <sub>oc</sub> (mV)	J <sub>sc</sub>	FF (%)	η (%)	Ref.
	techniques	of doped	(mAcm <sup>-2</sup> )	of doped	of doped	
		(undoped)	of doped	(undoped)	(undoped)	
		TiO <sub>2</sub>	(undoped)			
5mol% Nb	Hydrothermal synthesis	700 (790)	17.67 (11.87)	63 (70)	7.8 (6.6)	Lü et al., 2010
Nd	Solvothermal reactions	701 (707)	13.1 (10.7)	40.1 (36.6)	4.4 (3.3)	Yao et al., 2006
Bi	Sol-gel	590 (570)	7.71 ( 5.52)	46 (38)	2.11 (1.19)	An'amt et al., 2010
Та	Hydrothermal	870 (~750)	7.5 (8.1)	63 (68)	4.1 (4.06)	Feng et al., 2009

Table 5. Summarization of the performance of different metal-doped  $TiO_2$  and undoped  $TiO_2$  photoelectrodes for the application in DSSC

#### 3.1.4 Core-shell composite of titania (TiO<sub>2</sub>) and other metal-oxide for photoelectrode

Coating of TiO<sub>2</sub> with different metal oxide/hydroxide of wide band gap such as MgO, Nb<sub>2</sub>O<sub>5</sub>, ZnO, SrTiO<sub>3</sub>, Mg(OH)<sub>2</sub>, Zn(OH)<sub>2</sub> etc has received much attention for the improvement of the performance of DSSCs. Metal oxide/hydroxide coating on TiO<sub>2</sub> employed a core-shell structure, which is advantageous for the efficient photoconversion. Firstly, the wide band gap of shell metal oxide minimizes the electron-hole recombination by increasing the surface resistance of TiO<sub>2</sub> and retards the back electron transfer to the electrolyte. Secondly, the shell layer increases the dye absorption due to increased surface

area leading to high photoconversion and finally tuning the conduction band of core structure (Jung et al., 2005). Figure 10 depicts the different core-shell structure of metal oxide. The use of a thin metal oxide/hydroxide layer (shell) permitted the formation of an energy barrier at the electrode/electrolyte interface. It reduced the recombination rate and thereby improved the cell performance. The core-shell structure C in Figure 10 is favorable for the diffusion of the injected electrons because it does not face any energy barriers during the electron diffusion to the FTO (Chappel et al., 2002).



Fig. 10. Different geometries of core-shell electrodes showing that only in the core-shell matrix (c) the photoinjected electrons does not face any energy barriers during the diffusion to the TCO (redrawn with permission from, Chappel at al., 2002. Copyright 2010, The American Chemical Society)

Chen et al. prepared a new bilayer of Nb<sub>2</sub>O<sub>5</sub> coated nanoporous TiO<sub>2</sub> photoelectrode (Chen et al., 2001). The conduction band of shell materials Nb<sub>2</sub>O<sub>5</sub> is 100 mV negative than the core materials TiO<sub>2</sub>. Thus, the Nb<sub>2</sub>O<sub>5</sub> form an energy barrier to the photoelectrode and, therefore, confined the electrons to the core TiO<sub>2</sub> particles. This electron confinement to TiO<sub>2</sub> particles reduces the recombination and thereby increases the J<sub>sc</sub>. The increase of the photovoltage is attributed to the shift of the Fermi level of TiO<sub>2</sub> towards negative direction by Nb<sub>2</sub>O<sub>5</sub> (schematically describe in figure 11A). Consequently, all the cell parameter was improved and the overall cell efficiency enhanced up to 35%. Diamant et al. reported the development of SrTiO<sub>3</sub> coated TiO<sub>2</sub> (Diamant et al., 2003). This suitable band position of core-shell composite resulted in the increment of J<sub>sc</sub> by the reduced recombination as well as the efficient electron injection to FTO. Increment of V<sub>oc</sub> is attributed to the pervious phenomenon as Nb<sub>2</sub>O<sub>5</sub>-TiO<sub>2</sub> core shell photoelectrode. As a result, the overall DSSCs performance increased by 15%.

Nonmetal oxides such as  $CaCO_3$  with high band energy (6.0 eV) for the formation of favorable core-shell with  $TiO_2$  and high isoelectric point (IEP) to improve dye loading have also been explored. The increment of  $J_{sc}$  is mainly due to the high specific surface area of the CaCO<sub>3</sub> overlayer that caused the enhancement of dye loading up to 54%. The increased photovoltage is also attributed to the phenomenon described above with the more negative conduction band edge of CaCO<sub>3</sub> compare to that of TiO<sub>2</sub>. Overall, photo conversion increased by 24.4% with this approach (Lee at al., 2007).



Fig. 11. Schematic illustration of energy band tuning of TiO<sub>2</sub> photoelectrode (A) and SnO<sub>2</sub> photoelectrode (B) by the introduction of core-shell structure

The lower conduction band edge of SnO<sub>2</sub> compare to rutile TiO<sub>2</sub> makes it possible to switch the core-shell structure (i.e. TiO<sub>2</sub> as shell matrix and SnO<sub>2</sub> as core matrix). Reports are available for the formation of rutile TiO2 coated SnO2 hollow microsphere and nanoparticles. Qian et al. fabricated rutile TiO<sub>2</sub> coated SnO<sub>2</sub> hollow microsphere (MHS) for DSSCs photoelectrode (Qian et al., 2009). The Core-shell structure was characterized by scanning electron microscope (SEM), high-resolution transmission-electron microscope (HR-TEM), and x-ray diffraction (XRD). The XRD pattern of  $TiO_2$ -MHS is well indexed with the rutile structure of SnO<sub>2</sub> [space group P42/mnm (136)] with the additional rutile TiO<sub>2</sub> characteristics peak observed at  $2\theta$  = 36.09, 41.22, and 54.32<sup>0</sup>. The open circuit potential of  $TiO_2$ -SnO<sub>2</sub> MHS photoelectrode (V<sub>oc</sub> = 0.664 V) was higher than that of the pure SnO<sub>2</sub> photoelectrode ( $V_{oc}$  = 0.398 V) but lower than that of pure anatase TiO<sub>2</sub> photoelectrode ( $V_{oc}$ = 0.697 V). This is attributed to the fact that the conduction band of  $SnO_2$  is 300mV more positive than the rutile TiO<sub>2</sub>. Upon TiO<sub>2</sub> modification by SnO<sub>2</sub> MHS, the electronic band shifts to a more negative value (schematically describe in figure 11B). The open-circuit potential of TiO<sub>2</sub>-SnO<sub>2</sub> MHS is improved greatly. This indicates the effective suppression of interfacial electron recombination in TiO<sub>2</sub>-SnO<sub>2</sub> MHS electrode. J<sub>sc</sub> of the core-shell photoelectrode was observed higher than that of pure anatase TiO<sub>2</sub> photoelectrode. This is responsible for the formation of favorable energy barrier for efficient electron injection as depicted in figure 10C as well as the concurrent decrease of the recombination with increasing the surface resistance of SnO<sub>2</sub>. Chappel et al. observed a similar phenomenon by using rutile TiO<sub>2</sub> coated SnO<sub>2</sub> nanoparticle (Chappel et al., 2002). The different core-shell nanostructures photoelectrode and their performance for the application in DSSCs are summarized in Table 6.

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Core-shell	Synthesis techniques	V <sub>oc</sub> (mV) of modified (unmodified)	J <sub>sc</sub> (mAcm <sup>-2</sup> ) of modified (unmodified)	FF (%) of modified (unmodified)	η (%) of modified (unmodified)	Ref.
MgO- Coated TiO <sub>2</sub> NPs	Topotactic reaction	720 (640)	11.7 (10.2)	53.5 (47.3)	4.5 ( 3.1)	Jung et al., 2005
Nb <sub>2</sub> O5 Coated TiO2	Hydrothermal	730 (661)	11.4 (10.2)	51 (56.5)	4.97 (3.62)	Wang et at., 2001)
SrTiO <sub>3</sub> coated TiO <sub>2</sub>	Hydrothermal	708 (650)	10.2 ( 10.5)	58.4 (53.6)	4.39 (3.81)	Diamant et al., 2003
CaCO <sub>3</sub> - Coated TiO <sub>2</sub>	Topotactic thermal decomposition	668 (654)	21.92 (19.39)	66.1 (61.8)	9.68 (7.84)	Lee et al., 2007
Mg(OH) <sub>2</sub> coated	Cathodic deposition	758 (696)	6.61 (6.43)	74 (73.6)	3.7 (3.3)	Yum et al., 2006
TiO <sub>2</sub> coated SnO <sub>2</sub> MHS	Sol-gel	664 (697)	14.6 (11.07)	58.3 (66.6)	5.65 (5.14)	Qian et al., 2009

Table 6. Comparison performance of different core-shell modified and unmodified  $TiO_2$  and  $SnO_2$  photoelectrode for the application in DSSCs

## 3.2 Photoelectrode based on ZnO and its composite

Zinc oxide (ZnO) is an important class of semiconductor. It is almost insoluble in water, usually appears as white powder, and exists in nature usually as zincite mineral. Many superior physical properties such as the high electron mobility (~100 cm<sup>2</sup>/Vs), high thermal conductivity and stability, wide and direct band gap ( $E_g = -3.37$  eV at room temperature), large excitation binding energy (60 meV), large saturation velocity (3.2x107 cms-1) and high optical gain of 300 cm<sup>-1</sup> (100 cm<sup>-1</sup> for GaN) at room temperature make it as an attractive materials for wide range of application such as sensor, pigments in paint, filler in rubber products, thin film transistor, photodetectors, light emitting diode(LED) and in photovoltaic device (Rahman et al., 2010). The electronic configuration of ZnO is composed by completely filled 3*d*-orbital ( $3d^{10}$ ). The valence band of ZnO consists of only *d* orbital and the conduction band is composed by hybridized *s*-*p* orbitals. This type of electronic configuration of ZnO leads to the state of dissimilar parity with reduced (e-h<sup>+</sup>) recombination probability (Jose et al., 2009). Therefore, from the point of view of electronic configuration and excellencies in physical properties, ZnO is considered as a suitable material for the application in DSSC. There are three crystalline forms for ZnO: hexagonal wurtzite, cubic zincblende, and cubic rock salt. Among them, wurtzite is the most stable at ambient condition, lowest energy

structure, and most common form of crystal. Cubic zincblende can also be stabilized by growing cubic ZnO on substrate. However, the cubic rock salt (NaCl) type ZnO is observed very rarely at extremely high pressure of 10 G pa (Corso et al., 1994). Figure 12 shows the structure of two crystallographic form of ZnO (wurtzite and cubic zincblende), where the zinc (Zn) and oxygen centers are tetrahedral. The conduction band energy of hexagonal wurtzite ZnO is similar to that of the conduction band of TiO<sub>2</sub>. That's why; the hexagonal wurtzite ZnO has extensively explored for the development of efficient DSSCs and for the replacement of TiO<sub>2</sub> as well (Redmond et al., 1994). In this section, we will discuss on the potential application, prospects, and limitation of ZnO based photoelectode for the application in DSSCs.

Hupp and colleagues studied the electron transport properties in ZnO nanotube (64µm length) by EIS. It was observed that the electron transport is significantly faster and electron extracted more rapidly in ZnO nanotube compare to nanocrystalline TiO<sub>2</sub> (Martinson et at., 2009). On the other hand, Hagfeldt and coworkers suggested that the electron diffusion follows a trapping/detrapping mechanism in nanoporous ZnO. This trapping/detrapping is strongly dependent on the variation of film thickness, applied potential, and electrolyte system (Solbrand et al., 2000). It is estimated that the diffusion coefficient in ZnO photoelectrode is 10-6 cm<sup>2</sup>s<sup>-1</sup> at +300 mV vs Ag/AgCl in ethanol with 0.5 M LiClO<sub>4</sub> and 2x10-5 cm<sup>2</sup>s<sup>-1</sup> for nanoporous TiO<sub>2</sub> electrode under the same condition but in 0.7 M LiClO<sub>4</sub>. Therefore, electrons are more long lived in ZnO than in TiO<sub>2</sub> and that the electron losses to acceptors in solution and to deep traps are less for ZnO than for  $TiO_2$ . Despite these superior physical properties of ZnO, the highest reported efficiency of ZnO based DSSCs is still very low (ca. 6.58%). This might be due to the formation of  $Zn^{2+}/dye$  complex that inhibits the efficient electron injection and causes the retardation of the dye regeneration. The highly efficient acidic ruthenium (II) dyes (such as N3, N719, Black dye, etc.) generally showed lower performance with ZnO based photoelectrodes. It was attributed to the reduced chemical stability of ZnO due to the dissolution of ZnO and formation of aggregates which are caused by the proton release from the acidic dye. In order to improve the performance and stability of ZnO based photoelectrode, different strategies have been introduced. It includes the design and synthesis of suitable new dyes for ZnO photoelectrode, the development of quantum dot (QD) sensitized ZnO photoelectrode, and the development of 1-D ZnO photoelectrode for efficient photoelectron collection (Quintana et al., 2007; Zhang et al., 2009).

As discussed in the figure 7D, 1-D nanostructure makes the unidirectional electron diffusion possible and therefore increases the efficiency of electron injection and collection by reducing the recombination during the interparticle hopping process. Various types of 1-D ZnO, such as hierarchical ZnO nanowire-nanosheet, nanodisk, nanowire, nanorod, nanofibre, and nanocomb have been synthesized for the application in DSSCs. Figure 13 depicts the scanning electron microscopic (SEM) images of some of the 1-D ZnO nanostructures. Umar et al. fabricated highly crystalline ZnO nanocomb directly grown on FTO by noncatalytic hydrothermal evaporation process (Umar et al., 2009). However, ZnO nanocomb photoelectrode with N719 sensitization showed very low conversion efficiency of 0.86%, due to the low dye loading and fast interfacial recombination of electron and holes. The former is attributed to the low specific surface area of 1-D nanostructures of ZnO. This concurrently results in the increases of the recombination due to the enhancement of charge recombination at the uncovered oxide surface. This effect was minimized by the development of 1-D nanostructure with high aspect ratios and the various 1-D

nanostructures of ZnO used for DSSCs are summarized in Table 7. In brief, Wang et al. synthesized porous hierarchical ZnO nanodisk with higher surface area (21.8 m<sup>2</sup>g<sup>-1</sup>) by a simple low temperature hydrothermal method (Wang et al., 2010). Ramakrishna et al. developed ZnO nanofibres with even higher aspect ratio and surface area of 30 m<sup>2</sup>g<sup>-1</sup> (Zhang et al., 2009). Both showed the improvement of efficiencies up to 2.49 and 3.02% respectively mainly due to the improved dye loading.



Fig. 12. Crystallographic pattern of mostly observed and common hexagonal wurtzite crystal of ZnO (space group *P* 63*mc*) (a) and cubic zincblende (space group *F* 43*m*) (b). Where big red sphere Zn<sup>2+</sup>, small green sphere: O<sup>2-</sup>



Fig. 13. Scanning electron microscopic (SEM) image of different 1-D nanostructures of ZnO (A) Hierarchical ZnO nanowire-nanosheet,(B) nanodisk,(C) nanowire, and (D) nanorod.(reproduced with permission for ref. Xu et al., 2010; Wang et al., 2010; Gao et al., 2007; Pang et al., 2007. Copyright 2010, The American Chemical Society)

Metal Oxides and Their Composites for the Photoelectrode of Dye Sensitized Solar Cells

Materials	Synthesis process	Surface area (m <sup>2</sup> g <sup>-1</sup> )/	Sensitizer	V <sub>oc</sub> (V)	J <sub>sc</sub> (mAcm <sup>-2)</sup>	FF (%)	η (%)	Ref.
		aspect ratio						
ZnO	Noncatalytic	-	N719	0.67	3.14	34	0.68	Umar et
nanocomb	Thermal							al., 2009
	evaporation							
ZnO nanowire	Hydrothermal	-/100- 120	N719	0.54	6.79	50	1.7	Gao et al., 2007
ZnO nanorod	Hydrothermal	12.71/-	N719	0.73	3.41	74.4	1.86	Umar et al., 2009
ZnO nanodisk	Hydrothermal	21.8/-	N719	0.69	6.92	52.5	2.49	Wang et al., 2010
ZnO nanofibre	Electrospinning	30/-	N719	0.57	9.14	58	3.02	Zhang et al., 2009

Table 7. Summarization of different 1-D ZnO nanostructures, their physical properties, along with their performance in DSSCs

ZnO has been extensively explored as a composite material together with  $TiO_2$  for the application in DSSCs. The potential application of ZnO nanostructures as a scattering layer and core-shell nanostructures composites along with  $TiO_2$  has described in section 3.1.2 and 3.1.4. In this section, we need more focus on the hybrid nanocomposites of ZnO for the application in DSSC. In addition to the development of 1-D ZnO nanostructures with higher aspect ratio and surface area, many ZnO nanocomposites (shown in figure 14) have explored to improve the dye loading with maintaining the directional electron transport pathway as in 1-D nanostructures.



Fig. 14. Schematic illustration of different types of nanocomposites, (A) Hierarchical ZnO nanowire-nanosheet, (B) branched ZnO nanorod along with their directional electron transport. (redrawn with permission from ref. Xu et al., 2010; Cheng at al., 2008. Copyright 2010, The American Chemical Society)

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Cheng et al. fabricated a branched ZnO nanowire on FTO by hydrothermal method. The fabricated branched nanowires consists perpendicular and outspread branched nanowires (Cheng et al., 2008). The phototconversion efficiency of the branched nanowires is almost twice than that of ZnO nanowire. The enhancement of photocurrent was attributed to the increase of internal surface area of the branched structure for higher dye loading without the increase of interparticle hopes. The extended nanocomposites with extended optical path length were also partly responsible for higher photoconversion efficiency due to more light scattering. Jiang et al. introduced a flower like branched ZnO nanowire array (Jiang et al., 2007). Subsequently, Xu et al. synthesized hierarchical ZnO nanowire array (Jiang et al., 2007). Subsequently, Xu et al. synthesized hierarchical ZnO nanoarchitectures, consisting of ZnO nanowires on the nanosheets array (Xu et al., 2010). The photoconversion efficiency (*ca.* 4.8%) of this nanoarchitecture is more than double compare to its nanosheet counterpart photoelectrode. Table 8 shows the phoconversion parameters of some reported nanocomposites used for DSSCs.

Nanocomposites	Sensitizer	$V_{oc}(mV)$	$J_{sc}$ (mAcm <sup>-2</sup> )	FF (%)	η(%)	Ref.
ZnO nanowire	Mercurochrome	610	6.3	580	2.2	Ku & Wu,
array/nanoparticle						2007
ZnO nanoflower	N719	650	5.5	53	1.9	Jiang et al.,
						2007
Branched ZnO	N719	675	4.27	52.2	1.51	Cheng et al.,
Nanowires						2008
ZnO Nanowire-	N719	680	10.9	65	4.8	Xu et al.,
Nanosheet						2010

Table 8. Comparison of the photoconversion performance of different ZnO nanocomposite based photoelectrode in DSSCs

#### 3.3 Photoelectrode based on Nb<sub>2</sub>O<sub>5</sub> and SrTiO<sub>3</sub>

Niobium pentaoxide (Nb<sub>2</sub>O<sub>5</sub>) is another important type of wide band gap ( $E_g = \sim 3.49 \text{ eV}$ ) semiconductor and has been investigated for the development of photoelectrode materials for DSSCs. Nb<sub>2</sub>O<sub>5</sub> is appreciably explored as composite materials with TiO<sub>2</sub> as a core-shell structure discussed it the section 3.1.4. The higher band position of Nb<sub>2</sub>O<sub>5</sub> up to 250 mV relative to the TiO<sub>2</sub> makes it suitable for the formation of core-shell structure (Wei et al., 2008). Nb<sub>2</sub>O<sub>5</sub> has two different crystal structures of monoclinic and orthorhombic with the space group P2 and Pbam, respectively. The cell parameters of monoclinic crystal are a = 2038, b = 3.824, and c = 19.37 Å with  $\beta$  = 115.69<sup>o</sup> and for orthorhombic crystal, a = 6.168, b = 29.31, and c= 3.935 Å (Jose et al., 2009). The large unit cell dimension of Nb<sub>2</sub>O<sub>5</sub> is partly responsible for the reduction of surface area. The reduced surface area of Nb<sub>2</sub>O<sub>5</sub> causes the inefficient dye loading and results in the decrease of short circuit current. GuO et al. developed a single-crystal Nb<sub>2</sub>O<sub>5</sub> photoelectrode for the fabrication of DSSCs (Guo et al., 1999). The low surface area of the Nb<sub>2</sub>O<sub>5</sub> (25 m<sup>2</sup>g<sup>-1</sup>) compare to TiO<sub>2</sub> (104 m<sup>2</sup>g<sup>-1</sup>) showed relatively poor performance in DSSCs. Random movement of the injected electron into the single-crystal Nb<sub>2</sub>O<sub>5</sub> might be another factor for decreased photocurrent. Therefore, the efficiency of the DSSCs (active area 0.2 cm<sup>2</sup>) decreases from 5.0 to 2.2%. For scaling up the

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performance of Nb<sub>2</sub>O<sub>5</sub> based DSSCs, Wei et al. synthesized 1-D Nb<sub>2</sub>O<sub>5</sub> nanobelts for directional transport of electron to increase the photocurrent (Wei et al., 2008). Nevertheless, the main drawbacks of 1-D nanostructures are the drop off of surface area with decreased aspect ratios. Therefore, the decrease dye loading of the nanobelts results the poor conversion efficiency. It is noteworthy that the higher stability, higher conduction band energy of Nb<sub>2</sub>O<sub>5</sub> could be makes it suitable materials for the development of high efficient DSSCs like TiO<sub>2</sub>. Therefore, researchers should give more attention to develop the nanoporous Nb<sub>2</sub>O<sub>5</sub> nanoparticles and well defined 1-D nanostructures with different nanocomposites for the fabrication of DSSCs.

SrTiO<sub>3</sub> is a binary metal-oxide with high dielectric constant (~10<sup>4</sup>) and shares more structural similarities with anatse TiO<sub>2</sub>. Figure 15 depicts the perovskite-type cubic structure of SrTiO<sub>3</sub> of space group *Pm3m* and lattice parameter a = 3.9. Titanium atoms are in 6-fold octahedral coordination in SrTiO<sub>3</sub>, similar to the titanium arrangement in anatase TiO<sub>2</sub> (Lotnyk et al., 2007). The band gap of SrTiO<sub>3</sub> is ~3.2 eV and the conduction band is 0.2 eV above the conduction band of anatase TiO<sub>2</sub>. This suitable band position of SrTiO<sub>3</sub> makes it appropriate materials for the development of DSSCs photelectrode (Burnside et al., 1999). We described the core-shell structure of TiO<sub>2</sub>-SrTiO<sub>3</sub> in the section 3.1.4. In spite of the similar band gap of SrTiO<sub>3</sub> and anatase TiO<sub>2</sub>, the negative positioned of the conduction band of SrTiO<sub>3</sub> leads to the negative shift of the flat band (V<sub>FB</sub>) of SrTiO<sub>3</sub>. Therefore, the application of pure SrTiO<sub>3</sub> as photoelectrode will increase the photovoltage of DSSC.



Fig. 15. Crystallographic pattern of perovskite-type cubic structure of SrTiO<sub>3</sub> (space group Pm3m), where, big green sphere: Sr<sup>2+</sup>, grey sphere: Ti<sup>4+</sup>, and small red sphere: O<sup>2-.</sup>

Burnside et al. synthesized nanocrystalline  $SrTiO_3$  by hydrothermal treatment for the application in DSSCs (Burnside et al., 1999). The prepared photoelctrode sensitized by ruthenium (2, 2'-bipyridyl-4, 4'-dicarboxylate)<sub>2</sub>(NCS)<sub>2</sub>) showed the expected increment of  $V_{oc}$  (789 mV) compare to TiO<sub>2</sub> (686 mv). However, the photoconversion efficiency is very low due to the decreased  $J_{sc}$ . This might be due to the decreased surface area of nanocrystalline SrTiO<sub>3</sub>, lack of directional movement of electrons and the low dye uptake. In order to increase the performance of SrTiO<sub>3</sub> based DSSCs, research should be focused to develop new techniques for synthesizing highly porous nanoparticles of reduced size, 1-D

nanostructures for the efficient injection of electrons and to retard the recombination. Development of new dyes with more negative positioned LUMO level compare to other conventional dye would be another interest of research of  $SrTiO_3$  based DSSC. In this respect, Zaban and coworkers, developed a type-II DSSCs by utilizing  $SrTiO_3$  coated  $TiO_2$  for efficient electron injection by minimizing the back reaction (Hod et al., 2010). Since the conduction band of  $SrTiO_3$  is more negative than  $TiO_2$  and the LUMO of type-II sensitizer (catechol) is well above the conduction of  $TiO_2$ . Therefore, coating of  $TiO_2$  with  $SrTiO_3$  creates an energy barrier for efficient electron transfer from  $SrTiO_3$  to  $TiO_2$  and reduces the back electron transfer from oxidized dye. So an increase of  $J_{sc}$  (18%) and 70% charge collection improved the performance of DSSCs. No reports are available for the development of 1-D nanostructures of  $SrTiO_3$  and its application in DSSC. Therefore, more attention should be required for the development of 1-D nanostructure of  $SrTiO_3$  with high aspect ratios and exploring different dye for type-I and for type-II DSSCs.

# 4. Conclusion

This chapter discussed the structural aspects of various metal oxides and their composites. Interfacial electron transfer kinetics of dye/metal oxides and metal oxide/electrolyte for the conventional DSSCs were discussed. The alteration of interfacial electron transfer kinetics upon modification of the photoelectrode with metal oxide composite has also been described. In addition to the performance of different metal oxides and their composites in DSSC photoelectode, the fundamental aspects, the characterization methods, and the prospects and limitations of DSSCs were briefly explained. Various strategies for the sequential development of highly efficient DSSCs have been described and suggested nevertheless not satisfactory yet for the commercialization of DSSCs with high efficiency. The authors wish that this chapter can guide the researchers to understand the fundamental aspect and the stepwise development of different metal oxides and their composite for the photoelectrode of DSSCs.

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Due to their good mechanical characteristics in terms of stiffness and strength coupled with mass-saving advantage and other attractive physico-chemical properties, composite materials are successfully used in medicine and nanotechnology fields. To this end, the chapters composing the book have been divided into the following sections: medicine, dental and pharmaceutical applications; nanocomposites for energy efficiency; characterization and fabrication, all of which provide an invaluable overview of this fascinating subject area. The book presents, in addition, some studies carried out in orthopedic and stomatological applications and others aiming to design and produce new devices using the latest advances in nanotechnology. This wide variety of theoretical, numerical and experimental results can help specialists involved in these disciplines to enhance competitiveness and innovation.

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